S.Y.B.Sc. (With Credits)-Regular-Semester 2012 Sem IV B.Sc.24122 - Physics-II (Atomic Physics and Solid State Electronics) Paper- II

P. Pages : 3 Time : Three Hour			Iours GUG/W/16/ Max. Mar	GUG/W/16/5615 Max. Marks : 50	
	Note	es :	 All questions are compulsory. Draw neat labelled diagrams wherever necessary. 		
1.	Eith	ner			
	a)	i)	Describe Stern-Gerlach experiment with necessary theory. Discuss its significance.	7	
		ii)	Determine the maximum separation of a beam of hydrogen atom that move a distance of 20 cm with a speed of 2×10^5 m/s perpendicular to the magnetic field, whose gradient is 2×10^2 T/m and $M_H = 1.67 \times 10^{-27}$ kg. (Given $\mu_B = 9.27 \times 10^{-24}$ J/T)	3	
			OR		
	b)	i)	Define stability factor.	1	
		ii)	Explain the condition for faithful amplification.	2	
		iii)	Explain with neat circuit diagram the working of self bias method for stabilization.	4	
		iv)	Derive an expression for stability factor.	3	
2.	Eith	ner			
	a)	i)	Explain how MOSFET differ with FET.	2	
		ii)	Explain the construction and working of P-channel enhancement MOSFET.	5	
		iii)	In case of JFET, $V_{GS} = 0V$, $V_{DS} = 7V$, $I_D = 10$ mA. Now for $V_{GS} = 0V$, V_{DS} is changed to 15v, due to which I_D becomes 10.25mA. In the second state V_{GS} is change changed from 0 to 2V at $V_{DS} = 15$ V and drain current changes to 9.65mA. Determine a) r_d b) gm and c) μ OR	3	
	b)	i)	Explain the working of a difference amplifier with the help of circuit diagram.	4	
	,	íi)	Derive an expression for output voltage.	2	
		iii)	Explain why needed dual power supply for OP-AMP.	2	
		iv)	A difference amplifier has a difference mode gain 100 and CMRR = 100. Calculate the output voltage if the inputs are $V_1 = 1 mV$ and $V_2 = 0.9 mV$.	2	

3. Either

4.

5.

a)	Explain magnetic quantum number.	21/2				
b)	In a transistor circuit the emitter and collector currents are measured as 5mA and 4.9mA respectively. Calculate β of the transistor.	21/2				
c)	Define FET parameters and write the relation between them.	21/2				
d)	Explain the working of two stage RC coupled CE amplifier.	21/2				
OR						
e)	Explain space quantisation on the basis of vector atomic model.	21/2				
f)	Compare the areas and doping levels of the different regions of transistor.	21/2				
g)	Calculate the voltage gain of a common source JFET amplifier having transconductance 2500 μ mho and load resistance 5k Ω .	21/2				
h)	Explain the working of class A amplifier graphically.	21/2				
Eith	Either					
a)	Explain spinning of electron on the basis of vector atomic model.	21/2				
b)	Explain the working of PNP transistor.	21/2				
c)	What are advantage of FET over BJT.	21/2				
d)	A non-inverting amplifier has input resistance of $10k\Omega$ and feedback resistance of $20k\Omega$. Calculate the output voltage if the input voltage is 0.5 volt.	21/2				
	OR					
e)	Name the four quantum numbers of an electron and explain principle quantum number.	21/2				
f)	Explain the output characteristic of transistor in CE mode.	21/2				
g)	Derive an expression for voltage gain of common source amplifier.	21/2				
h)	Explain OP-AMP use as a summing amplifier.	21/2				
	Attempt any ten questions from the following.					
	a) What is Zeeman effect?	1				
	b) State Pauli's exclusion principal.	1				

c) What is L-S coupling?

d) For a given transistor $\beta = 50$, calculate its α .

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e)	What is heat sink?	1
f)	Define current gain in CB mode.	1
g)	Draw circuit symbol of n-channel and p-channel depletion MOSFET.	1
h)	Write the application of JFET.	1
i)	Why does a MOSFET have very high input impedance?	1
j)	What is open loop voltage gain?	1
k)	Write two characteristic of ideal OP-AMP.	1
l)	What is an oscillators?	1
